

isc Silicon NPN Power Transistor

2SC3258

DESCRIPTION

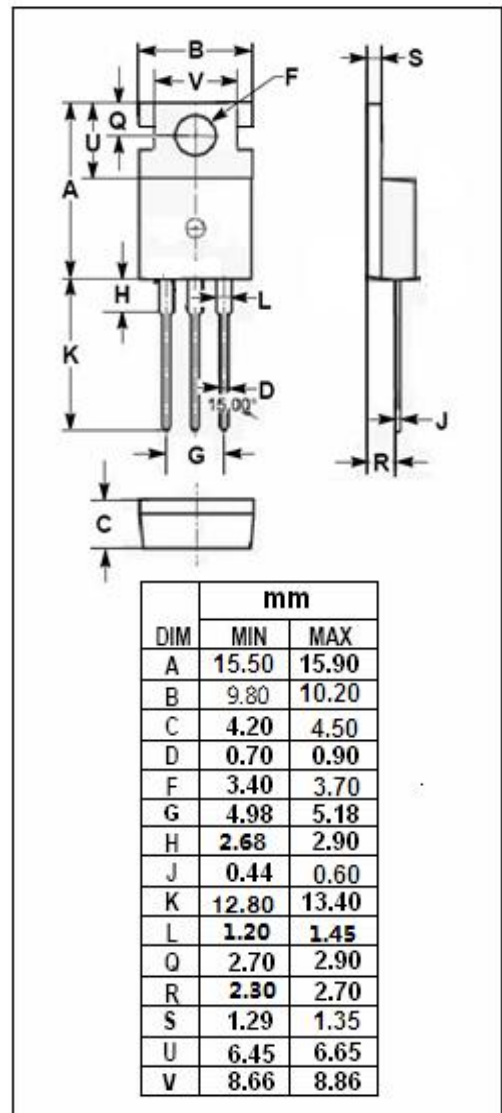
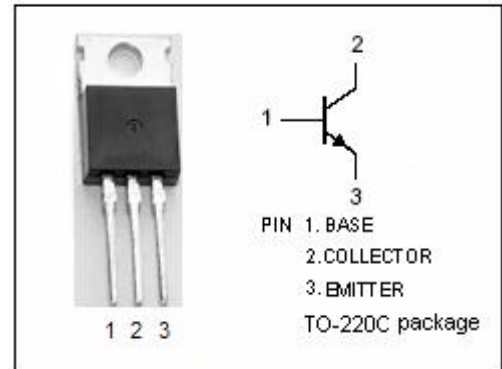
- Low Collector Saturation Voltage-
: $V_{CE(sat)} = 0.4V(\text{Max.}) @ I_C = 3A$
- High Switching Speed
- Complement to Type 2SA1293
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

- Designed for high current switching applications.

ABSOLUTE MAXIMUM RATINGS($T_a = 25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{CBO}	Collector-Base Voltage	100	V
V_{CEO}	Collector-Emitter Voltage	80	V
V_{EBO}	Emitter-Base Voltage	7	V
I_C	Collector Current-Continuous	5	A
I_{CM}	Collector Current-Peak	8	A
I_B	Base Current-Continuous	1	A
P_C	Collector Power Dissipation @ $T_C = 25^\circ\text{C}$	30	W
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature Range	-55~150	$^\circ\text{C}$



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ELECTRICAL CHARACTERISTICS

 $T_C=25^{\circ}\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_C = 10\text{mA}; I_B = 0$	80			V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 3\text{A}; I_B = 0.15\text{A}$			0.4	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = 3\text{A}; I_B = 0.15\text{A}$			1.2	V
I_{CBO}	Collector Cutoff Current	$V_{CB} = 100\text{V}; I_E = 0$			1.0	μA
I_{EBO}	Emitter Cutoff Current	$V_{EB} = 7\text{V}; I_C = 0$			1.0	μA
h_{FE-1}	DC Current Gain	$I_C = 1\text{A}; V_{CE} = 1\text{V}$	70		240	
h_{FE-2}	DC Current Gain	$I_C = 3\text{A}; V_{CE} = 1\text{V}$	40			
f_T	Current-Gain—Bandwidth Product	$I_C = 1\text{A}; V_{CE} = 4\text{V}$		120		MHz
C_{OB}	Output Capacitance	$I_E = 0; V_{CB} = 10\text{V}; f_{test} = 1.0\text{MHz}$		80		pF

Switching times

t_{on}	Turn-On Time	$I_{B1} = -I_{B2} = 0.15\text{A}; R_L = 10\Omega;$ $V_{CC} \approx 30\text{V}$		0.2		μs
t_{stg}	Storage Time			1.0		μs
t_f	Fall Time			0.1		μs

◆ h_{FE-1} Classifications

O	Y
70-140	120-240

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